

TECHNICAL INFORMATION

SILICON JUNCTION RECTIFIER

> **TYPE CK775**

> > 5/8" max.

The CK775 is a hermetically sealed, high temperature, high current silicon rectifier. It is designed to operate at ambient temperatures in the range of - 55 to + 170 ° C.

MECHANICAL DATA

CASE: Metal and Glass

TERMINALS: Cathode: ¼-28 bolt Anode: Terminal Lug for 8-32 bolt.

MOUNTING POSITION: Any

ELECTRICAL DATA

RATINGS -	ABSOLUTE	MAXIMUM	VALUES
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	WITH HEAT RADIATOR			
Case Temperature A RMS Voltage Peak Inverse Voltage Average Rectified Current RMS Rectified Current Peak Rectified Current Dissipation	30 40 60 15 25 50 40	70 40 60 10 15 30 20	170 °C 40 volts 60 volts 5 amperes 7-5 amperes 15 amperes 10 watts	
	WITH NO HEAT RADIATOR			
Ambient Temperature RMS Voltage Peak Inverse Voltage Average Rectified Current RMS Rectified Current Peak Rectified Current		25 40 60 2.0 3.0 6.0	170 °C 40 volts 60 volts 0.5 amperes 0.7 amperes 1.5 amperes	
CHARACTERISTICS: (at 25°C)				
Maximum Forward Voltage at 5.0 amperes Maximum Reverse Current at 50 volts Maximum Reverse Current at 60 volts			1.5 volts 15 ma. 25 ma.	

A These ratings assume the rectifier is maintained at or below the specified case temperature by means of external cooling such as a heat dissipator. The case temperature should be measured at the circumference of the copper base. The temperature may be determined by use of a thermocouple or such indicators as temperature sensitive lacquers.

NOTE

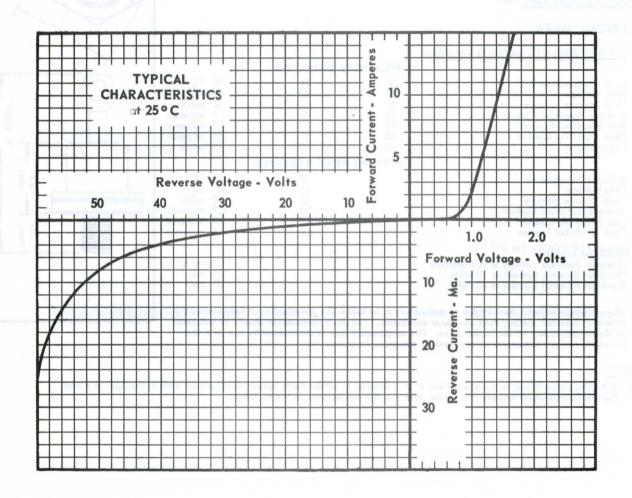
When making connections to the electrodes, if it is desired to solder these connections, a heat sink in the form of a pair of pliers should be used between the solder joint and the connections to the rectifier.

Tentative Data

RAYTHEON MANUFACTURING COMPANY



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